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#### **TPS62480**

SLVSCL9A-FEBRUARY 2016-REVISED FEBRUARY 2016

# TPS62480 2.4-V to 5.5-V, 6-A, 2-Phase Step-Down Converter

## 1 Features

- Dual Phase Current Mode Topology
- Input Voltage Range 2.4 to 5.5 V
- Output Voltage Range 0.6 to 5.5 V
- Output Current of 6 A
- Typical Quiescent Current of 23 µA
- Feedback Voltage Accuracy of ±1% (PWM Mode)
- Output Voltage Select
- Phase Shifted Operation
- Automatic Power Save Modes
- Forced PWM Mode
- Adjustable Soft Start
- Power Good / Thermal Good Outputs
- Undervoltage Lockout
- Overcurrent and Short-Circuit Protection
- Overtemperature Protection
- 3 × 2.5 mm HotRod<sup>™</sup> Package

## 2 Applications

- Low Profile Point-of-Load Supply
- Solid State Drives
- Ultra Portable/Tablet/Embedded PC
- Optical Modules, CMOS Cameras
- Wireless Modules, Network Cards

## 3 Description

The TPS62480 is a synchronous 2-phase step-down DC-DC converter for low profile point-of-load power supplies. The input voltage range of 2.4 to 5.5 V enables operation from typical 3.3-V or 5-V interface supplies as well as from backup circuits dropping down as low as 2.4 V. The output current is up to 6 A continuously provided by two phases of 3 A each, allowing the use of low-profile external components. Both the rails are running out of phase, reducing pulse current noise significantly.

The TPS62480 provides an automatically entered power save mode to maintain high efficiency down to very light loads. This incorporates an automatic phase adding and shedding feature using both or only one phase according to the actual load.

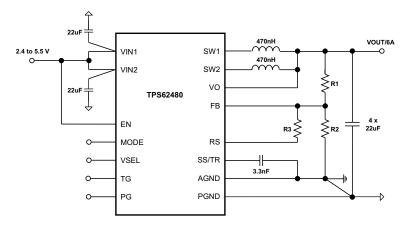
The device features a Power Good signal and an adjustable soft start. Also, the device features a Thermal Good signal to detect excessive internal temperature. The output voltage can be changed to a preselected value by VSEL pin. TPS62480 is able to operate in 100% duty cycle mode.

The TPS62480 is packaged in a small 3 × 2.5 mm HotRod<sup>™</sup> package (RNC).

#### Device Information<sup>(1)</sup>

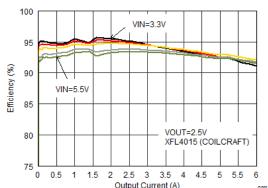
PART NUMBER	PACKAGE	BODY SIZE (NOM)		
TPS62480	VQFN (16)	3.00 × 2.50 mm		

(1) For all available packages, see the orderable addendum at the end of the data sheet.



## Typical Application Schematic

### **Efficiency vs Output Current**



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# 4 Revision History

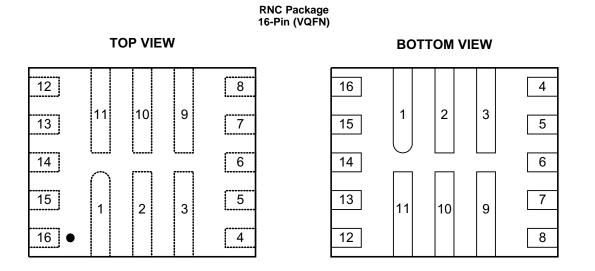
Cł	nanges from Original (February 2016) to Revision A	Page
•	Changed RCN Package To: RNC Package in <i>Pin Configuration and Functions</i>	3
•	Changed RCN 16 PINS To: RNC 16 PINS in the Thermal Information table	4
•	Changed the Test Conditions for $I_{SD}$ Shutdown Current From: EN = Low ( $\leq 0.4$ V) To: EN = Low ( $\leq 0.3$ V) in the <i>Electrical Characteristics</i>	5
•	Changed the VOUT Feedback Voltage Accuracy, MAX value From: 25% To: 2.5% in the Electrical Characteristics	<mark>6</mark>
•	Changed TPS62480RCN To: TPS62480RNC in Table 1	13

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# 5 Pin Configuration and Functions



### **Pin Functions**

PIN I/O		1/0	DECODUCTION	
NAME	NO.	1/0	DESCRIPTION	
PGND1	1		Power Ground Phase 1 (master)	
SW1	2		Switch Node Phase 1 (master), connected to the internal MOSFET switches	
VIN1	3		Supply voltage Phase 1 (master)	
EN	4	I	Enable input (High=Enabled, Low = Disabled)	
PG	5	0	Power Good (open drain, requires pull-up resistor)	
VSEL	6	I	Output Voltage Select (High = VOUT2, Low=VOUT1), VOUT1 < VOUT2	
TG	7	0	Thermal Good (open drain, requires pull-up resistor)	
MODE	8	Ι	Operating mode selection (Low=Automatic PWM/PSM, High = Forced PWM)	
VIN2	9		Supply voltage Phase 2	
SW2	10		Switch node Phase 2, connected to the internal MOSFET switches	
PGND2	11		Power Ground Phase 2	
SS/TR	12	0	Soft-Start / Tracking. An external capacitor connected to this pin sets the output voltage rise time.	
AGND	13		Analog Ground	
FB	14		Output voltage feedback for the adjustable version. Connect resistive voltage divider to this pin.	
RS	15		Resistor Select. Connect resistor that sets the level for the second output voltage here (activated by VSEL= High)	
VO	16		VOUT detection (connect to VOUT, output discharge is internally connected to this pin)	

# **6** Specifications

## 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) <sup>(1)</sup>

		MIN	MAX	UNIT
	VIN	-0.3	6	V
Din Voltogo Dongo <sup>(2)</sup>	SW1, SW2	-0.3	V <sub>IN</sub> +0.3	V
Pin Voltage Range <sup>(2)</sup>	EN, VSEL, MODE, SS/TR, PG, TG	-0.3	6	V
	FB, RS	-0.3	3	V
Power Good / Thermal Good Sink Current	PG, TG		10	mA
Operating Junction Temperature Range, $T_J$		-40	150	°C
Storage Temperature Range, T <sub>stg</sub>		-65	150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltages are with respect to network ground terminal.

# 6.2 ESD Ratings

			VALUE	UNIT
		Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins <sup>(1)</sup>	±1000	
V <sub>(ESD)</sub>	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all $\ensuremath{\text{pins}}^{(2)}$	±500	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

# 6.3 Recommended Operating Conditions

over operating junction temperature range (unless otherwise noted)

	MIN	ТҮР	MAX	UNIT
Supply Voltage Range, V <sub>IN</sub>	2.4		5.5	V
Output Voltage Range, V <sub>OUT</sub>	0.6		5.5	V
Maximum Output Current, I <sub>OUT</sub>	6			А
Operating junction temperature, T <sub>J</sub>	-40		125	°C

### 6.4 Thermal Information

			TPS62	UNIT	
	THERMAL METRIC <sup>(1)</sup>	RNC 16			
		JEDEC with thermal vias <sup>(2)</sup>	JEDEC standard		
$R_{\theta JA}$	Junction-to-ambient thermal resistance		26.4	56.4	°C/W
R <sub>0JC(top)</sub>	Junction-to-case (top) thermal resistance		32.2	32.2	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance		10.2	26.5	°C/W
Ψ <sub>JT</sub>	Junction-to-top characterization parameter		0.9	1.3	°C/W
Ψ <sub>JB</sub>	Junction-to-board characterization parameter		10.2	26.5	°C/W
R <sub>0JC(bot)</sub>	Junction-to-case (bottom) thermal resistance		-	-	°C/W

For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, SPRA953.
 See the *Layout* section.

### 6.5 Electrical Characteristics

over operating junction temperature range ( $T_J = -40^{\circ}$ C to 125°C) and  $V_{IN} = 2.4$  V to 5.5 V. Typical values at  $V_{IN} = 3.6$  V and  $T_J = 25^{\circ}$ C (unless otherwise noted).

	PARAMETER	ER TEST CONDITIONS		MIN	TYP	MAX	UNIT
SUPPLY		I					
\ <i>\</i>		V <sub>IN</sub> rising		2.6		5.5	
V <sub>IN</sub>	Input Voltage Range	V <sub>IN</sub> falling		2.4		5.5	V
Ι <sub>Q</sub>	Operating Quiescent Current	switching,	$ \begin{array}{l} EN = High, \ V_{IN} \geq 3 \ V, \ I_{OUT} = 0 \ mA, \ device \ not \\ switching, \\ T_J = -40^\circ C \ to \ +85^\circ C \end{array} $		23	38	μA
		100% Mode o	peration		3.5	6.5	mA
I <sub>SD</sub>	Shutdown Current	$EN = Low (\leq 0)$	$.3 \text{ V}), \text{ T}_{\text{J}} = -40^{\circ}\text{C} \text{ to } +85^{\circ}\text{C}$		0.5	18.5	μΑ
V <sub>UVLO</sub>	Undervoltage Lockout Threshold	Falling Input V	oltage	2.2	2.3	2.4	V
♥ UVLO	Undervoltage Lockout Threshold	Hysteresis			200		mV
т	Thermal Shutdown Temperature	PWM Mode, R	lising Junction Temperature		160		°C
T <sub>SD</sub>	Thermal Shutdown Hysteresis	PWM Mode			10		C
CONTROL	(EN, VSEL, MODE, SS/TR, PG, TG)						
V <sub>H</sub>	Input Threshold Voltage (EN, VSEL, MODE)	to ensure High	n Level	1.2			V
VL	Input Threshold Voltage (EN, VSEL, MODE)	to ensure Low	Level			0.4	v
I <sub>LKG(EN)</sub>	Input Leakage Current (EN)	EN = V <sub>IN</sub> or G	ND		10	200	nA
I <sub>LKG(MODE)</sub>	Input Leakage Current (MODE, VSEL)				10	200	nA
I <sub>SS/TR</sub>	SS/TR pin source current			4.7	5.25	5.8	μA
V <sub>TH(TG)</sub>	Thermal Good Threshold Temperature	PWM Mode			120		°C
(	Thermal Good Hysteresis	PWM Mode			10		
		Rising (%V <sub>OUT</sub>	-)	93%	96%	99%	
V <sub>TH(PG)</sub>	Power Good Threshold Voltage	Falling (%V <sub>OU</sub>	г)	89%	92%	95%	
V <sub>L(PG)</sub>	Output Low Threshold (PG, TG)	I <sub>PG</sub> = -2 mA				0.4	V
I <sub>LKG(PG)</sub>	Input Leakage Current (PG)				2	700	nA
I <sub>LKG(TG)</sub>	Input Leakage Current (TG)				2	100	nA
t <sub>SS</sub>	Internal Soft-Start Time	SS/TR = V <sub>IN</sub> o	r floating		80		μs
t <sub>DELAY</sub>	Time from EN rising until start switching			100	200	400	μs
POWER SV	WITCH						
	High-Side MOSFET ON-Resistance		Phase1 Phase2	-	36	98	mΩ
R <sub>DS(ON)</sub>	Low-Side MOSFET ON-Resistance	– V <sub>IN</sub> ≥ 3 V	Phase1 Phase2	-	29	72	mΩ
I <sub>LIM</sub>	High-Side MOSFET Current Limit	per phase		4.3	5.0	5.8	A

## **Electrical Characteristics (continued)**

over operating junction temperature range ( $T_J = -40^{\circ}$ C to 125°C) and  $V_{IN} = 2.4$  V to 5.5 V. Typical values at  $V_{IN} = 3.6$  V and  $T_J = 25^{\circ}$ C (unless otherwise noted).

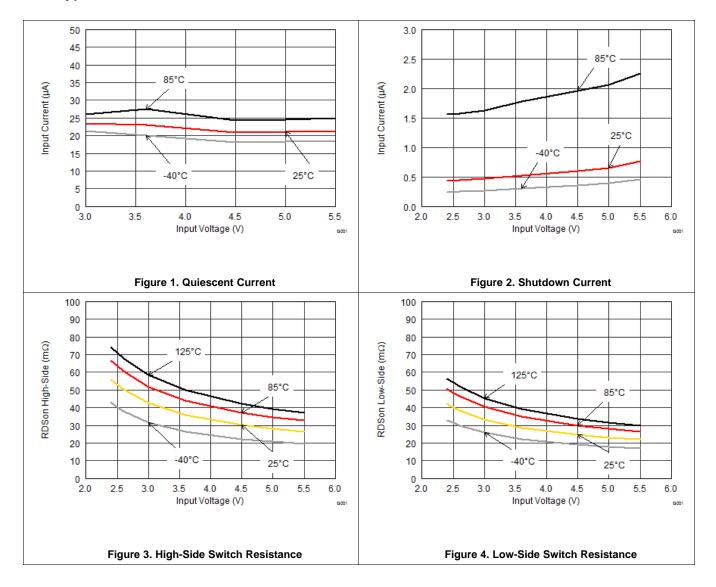
	PARAMETER TEST CONDITIONS		MIN	TYP	MAX	UNIT	
OUTPUT							
V <sub>REF</sub>	Internal Reference Voltage				0.6		V
I <sub>LKG(FB)</sub>	Input Leakage Current (FB)		V <sub>FB</sub> = 0.6 V		1	65	nA
I <sub>LKG(RS)</sub>	Input Leakage Current (RS)	EN = High	VSEL = Low, V <sub>RS</sub> = 0.6 V		1	65	nA
R <sub>RS</sub>	Internal resistance (RS to GND)		VSEL = High, I <sub>RS</sub> = 1 mA		10	50	Ω
V <sub>OUT</sub>	Output Voltage Range	V <sub>IN</sub> ≥ V <sub>OUT</sub>	V <sub>IN</sub> ≥ V <sub>OUT</sub>			5.5	V
		PWM Mode,	$T_J = -20^{\circ}C$ to $85^{\circ}C$	-1%		1%	
V <sub>OUT</sub>	Feedback Voltage Accuracy	V <sub>IN</sub> ≥ V <sub>OUT</sub> + 1 V	$T_J = -40^{\circ}C$ to $125^{\circ}C$	-1.4%		1.3%	
V <sub>OUT</sub>	Feedback Voltage Accuracy	Power Save Mod C <sub>OUT</sub> = 4 x 22 µl	de, L = 0.47 μH, F <sup>(1)</sup>	-1.4%		2.5%	
	Output Discharge Current <sup>(2)</sup>	EN = Low, V <sub>OUT</sub> = 2.5 V			120		mA
	Load Regulation	V <sub>OUT</sub> = 1.8 V, PWM mode operation		0.02			%/A
	Line Regulation	$2.6 \text{ V} \le \text{V}_{\text{IN}} \le 5.5 \text{ V}, \text{ V}_{\text{OUT}} = 1.8 \text{ V}, \text{ I}_{\text{OUT}} = 6 \text{ A},$ PWM mode operation			0.02		%/V

(1) The output voltage accuracy in Power Save Mode can be improved by increasing the output capacitor value, reducing the output voltage ripple.

(2) For detailed information on output discharge see *Active Output Discharge*.



### 6.6 Typical Characteristics



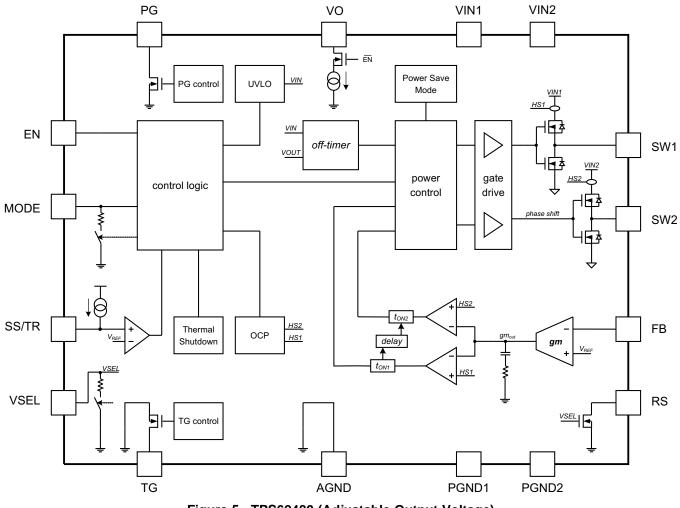


# 7 Detailed Description

## 7.1 Overview

The TPS62480 is a high efficiency synchronous switched mode step-down converter based on a 2-phase peak current control topology. It is designed for smallest solution size low-profile applications, converting a 2.4 V to 5.5 V input voltage into a lower 0.6 V to 5.5 V output voltage. While an outer voltage loop sets the regulation threshold for the inner current loop, based on the actual  $V_{OUT}$  level, the inner current loop regulates to the actual peak inductor current level for every switching cycle. The regulation network is internally compensated. While the ON-time is determined by duty cycle, inductance and cycle peak current, the switching frequency of typically 2.2 MHz is set by a predicted OFF-time. The device features a Power Save Mode (PSM) to keep the conversion efficiency high over the whole load current range.

The TPS62480 is a 2-phase converter, sharing the load among the phases. Identical in construction, the second phase control is connected with an adaptive delay to the first phase. Both the phases use the same regulation threshold and cycle-by-cycle peak current setpoint. This ensures a phase-shifted as well as current-balanced operation. Using the advantages of the 2-phase topology, a 6-A continuous output current is provided with high performance and as small as possible solution size.



## 7.2 Functional Block Diagram

Figure 5. TPS62480 (Adjustable Output Voltage)



#### 7.3 Feature Description

#### 7.3.1 Enable / Shutdown (EN)

The device starts operation, when VIN is present and enable (EN) is set High. Since the boundary EN thresholds are specified with 1.2 V for rising and 0.4 V for falling voltages, the typical vales are 0.85 V (rising) and 0.65 V (falling). The device is disabled by pulling EN Low. Leaving the EN pin floating is not recommended.

#### 7.3.2 Soft Start (SS), Pre-biased Output

The internal soft start circuit controls the output voltage slope during startup. This avoids excessive inrush current and provides an adjustable controlled output-voltage rise time. The soft start also prevents unwanted voltage drop from high impedance power sources or batteries.

When EN is set to start device operation, the device starts switching after a delay of typically 200 µs and VOUT rises with a slope, controlled by the external capacitor which is connected to the SS/TR pin (soft start). Leaving the SS/TR pin floating or connecting to VIN provides internally set fastest startup with a soft start slope of about 80us. See *Application Curves* for typical startup operation.

The device can start into a pre-biased output. In this case, the device starts switching, only when the internal set point for VOUT increases above the pre-biased voltage level.

#### 7.3.3 Tracking (TR)

The device tracks an external voltage applied to the SS/TR pin. The FB voltage tracks the external voltage as long as it is below about 0.6V. Above 0.6V the device goes to normal operation. If the voltage at the SS/TR pin decreases below about 0.6V, the FB voltage tracks again this voltage. See *Tracking* for further details.

#### 7.3.4 Output Voltage Select (VSEL)

A resistive divider (VOUT to FB to AGND) sets the output voltage of the TPS62480. Providing a logic High level at the VSEL pin, another resistor, connected between FB and RS pins is connected in parallel to the lower resistor of the divider. This sets a different higher output voltage and can be used for dynamic voltage scaling (see Setting V<sub>OUT2</sub> Using the VSEL Feature).

If the VSEL pin is set Low, the device connects an internal pull down resistor to keep the internal logic level Low, even if the pin is floating afterwards. The device disconnects the resistor, if the pin is set to High.

#### 7.3.5 Forced PWM (MODE)

To avoid *Power Save Mode (PSM) Operation*, the device can be forced to PWM mode operation by pulling the MODE pin High. In this case the device operates continuously with it's nominal switching frequency and the minimum peak current can go as low as -500 mA.

If the MODE pin is set Low, the device connects an internal pull down resistor to keep the internal logic level Low, even if the pin is floating afterwards. The device disconnects the resistor, if the pin is set to High.

#### 7.3.6 Power Good (PG)

The TPS62480 has a built in power good function. The PG pin goes High, when the output voltage has reached its nominal value. Otherwise, including when disabled, in UVLO or thermal shutdown, PG is Low. The PG pin is an open drain output that requires a pull-up resistor and can sink typically 2mA. If not used, the PG pin can be left floating or grounded.

### 7.3.7 Thermal Good (TG)

As long as the junction temperature of the TPS62480 is below the thermal good temperature of typically 120°C, the logic level at the TG pin is High. If the junction temperature exceeds that temperature, the TG pin goes Low. This can be used for the system to take action preventing excessive heating or even thermal shutdown. The TG pin is an open drain output that requires a pull-up resistor and can sink typically 2mA. If not used, the TG pin can be left floating or grounded.



#### **Feature Description (continued)**

#### 7.3.8 Active Output Discharge

The VO pin, connected to the output voltage, provides an active discharge path when the device is switched off by setting EN Low or UVLO event. In case of being activated, this discharge circuit sinks typically 120mA for output voltages of typically 1 V and above. If  $V_{OUT}$  is lower, the active current sink enters linear operation mode and the discharge current decreases.

#### 7.3.9 Undervoltage Lockout (UVLO)

The undervoltage lockout prevents misoperation of the device, if the input voltage drops below the UVLO threshold which is set to typically 2.3 V. The converter starts operation again once the input voltage exceeds the threshold by a hysteresis of typically 200 mV.

#### 7.3.10 Thermal Shutdown

The junction temperature  $(T_J)$  of the device is monitored by an internal temperature sensor. If  $T_J$  exceeds 160°C (typical), the device goes in thermal shutdown with a hysteresis of about 10°C. Both the power FETs are turned off and the PG pin goes Low. Once  $T_J$  has decreased enough, the device resumes normal operation with Soft Start.

#### 7.4 Device Functional Modes

#### 7.4.1 Pulse Width Modulation (PWM) Operation

The TPS62480 is based on a predictive OFF-time peak current control topology, operating with PWM in continuous conduction mode for heavier loads. The switching frequency is typically 2.2MHz. Both the master and follower phase regulate to the same VOUT level, each with a separate current loop, using the same peak current set point, cycle by cycle. This provides excellent peak current balancing, independent of inductor dc resistance matching. Since the follower phase operates with an adaptive delay to the master phase, phase shifted operation is always obtained. If the load current decreases, the device runs with the master phase only (see *Phase Add/Shed and Current Balancing*).

PWM only mode can be forced by pulling MODE pin High. If MODE is set Low, the device features an automatic transition into Power Save Mode, entered at light loads, running in discontinuous conduction mode (DCM).

#### 7.4.2 Power Save Mode (PSM) Operation

As the load current decreases to half the ripple current, the converter enters Power Save Mode operation. During PSM, the converter operates with reduced switching frequency maintaining high conversion efficiency. Power Save Mode is based on an adaptive peak current target, to keep output voltage ripple low. Since each pulse shifts  $V_{OUT}$  up, a pause time happens until  $V_{OUT}$  trips the internal  $V_{OUT\_Low}$  threshold again and the next pulse takes place.

The switching frequency in PSM (one phase operation) calculates as:

$$f_{SW(PSM)} = \frac{2 \cdot I_{OUT} \cdot V_{OUT} (V_{IN} - V_{OUT})}{L \cdot I_{PEAK}^2 \cdot V_{IN}}$$

(1)



#### **Device Functional Modes (continued)**

#### 7.4.3 Minimum Duty Cycle and 100% Mode Operation

The minimum on-time, which is typically 70ns, normally determines a limit on the minimum operating duty cycle. The calculation is:

$$DC_{min} = 70ns \cdot 100\% \cdot f_{SW}[Hz]$$

However, a frequency foldback lowers the switching frequency depending on the duty cycle and ensures proper regulation for every duty cycle.

There is no limit towards maximum duty cycle. When the input voltage becomes close to the output voltage, the device enters automatically 100% duty cycle mode and both high-side FETs switch on as long as VOUT remains below the regulation setpoint. In this case, the voltage drop across the high-side FETs and the inductors determines the output voltage level. An estimate for the minimum input voltage to maintain output voltage regulation is:

$$V_{IN(min)} = V_{OUT(min)} + I_{OUT} \left[ \frac{R_{DS(ON)}}{2} + DCR_{L1} // DCR_{L2} \right]$$
(3)

In 100% duty cycle mode, the low-side FETs are switched off. The typical quiescent current in 100% mode is 3.5 mA.

#### 7.4.4 Phase Shifted Operation

Using an inherent benefit of the two-phase conversion, the two phases of TPS6248X run out of phase. For every switching cycle, the second phase is not allowed to turn on its high-side FET until the master phase has reached its peak current value. This limits the input RMS current and corresponding switching noise.

#### 7.4.5 Phase Add/Shed and Current Balancing

When the load current is below the internal threshold, only the master phase operates. The second phase activates, if the load current exceeds the threshold of typically 1.7 A. The second phase powers off with a hysteresis of about 0.5 A, when the load current decreases.

Since the internal circuitry and layout matches both phase circuits, the peak currents balance with less than 15% deviation at heavy loads. This is independent of the inductor's tolerance. However, the maximum peak current, specified as High-Side MOSFET Current Limit in *Electrical Characteristics* is not exceeded at any time. A detailed example about current balancing is given in Figure 28.

#### 7.4.6 Current Limit and Short Circuit Protection

Each phase has a separate integrated peak current limit. The dc values are specified in the *Electrical Characteristics*. While its minimum value limits the output current of the phase, the maximum number gives the current that must be considered to flow in some operating case. At the peak current limit, the device provides its maximum output current.

However, if the current limit situation remains for 512 consecutive switching cycles, the peak current folds back to about 1/3 of the regular limit. This limits the output power for over current and short circuit events. The foldback current limit is released to the normal one only if the load current has decreased as far as needed to undercut the (foldback) peak current limit.

(2)



# 8 Application and Implementation

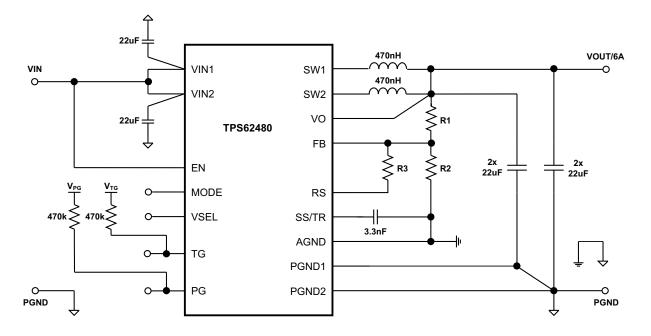
#### NOTE

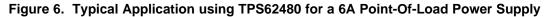
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 8.1 Application Information

The TPS62480 is a switched mode step-down converter, able to convert a 2.4-V to 5.5-V input voltage into a lower 0.6-V to 5.5-V output voltage, providing up to 6 A continuous output current. It needs a minimum amount of external components. Apart from the LC output filter and the input capacitors, additional resistors or capacitors are only needed to enable features like soft start, adjustable and selectable output voltage as well as Power Good and/or Thermal Good.

## 8.2 Typical Application





### 8.2.1 Design Requirements

The following design guideline provides a range for the component selection to operate within the recommended operating conditions. Table 1 shows the components selection that was used for the measurements shown in the *Application Curves*.

### **Typical Application (continued)**

#### Table 1. List of Components

REFERENCE	DESCRIPTION	MANUFACTURER
IC	5.5-V, 6-A step-down converter, QFN	TPS62480RNC, Texas Instruments
L	2x0.47-µH ±20%, (2.5x2x1.2) mm	DFE252012P-R47M, Toko
Cin	2x22-µF, 10-V, ceramic, 0603, X5R	GRM188R61A226ME15#, muRata
Cout	4x22-µF, 25-V, ceramic, 0805, X5R	GRM21BR61E226ME44L, muRata
Css	3300-pF, 10-V, ceramic, 0402	Standard
R1	Depending on Vout1, chip, 0402, 0.1%	Standard
R2	Depending on Vout1, chip, 0402, 0.1%	Standard
R3	Depending on Vout2, chip, 0402, 0.1%	Standard
R4, R5	470-kΩ, chip, 0603, 1/16-W, 1%	Standard

#### 8.2.2 Detailed Design Procedure

#### 8.2.2.1 Setting the Adjustable Output Voltage

While the device regulates the FB voltage to 0,6V, the output voltage is specified from 0.6 to 5.5 V. A resistive divider (from VOUT to FB to AGND) sets the actual output voltage of the TPS62480. Equation 4 and Equation 5 are calculating the values of the resistors. First, determining the current through the resistive divider leads to the total resistance ( $R_1 + R_2$ ). A minimum divider current of about 5  $\mu$ A is recommended and can be higher if needed.

$$R_{1} + R_{2} = \frac{V_{OUT}}{I_{FB}}$$

$$R_{2} = \frac{V_{REF}}{V_{OUT}} (R_{1} + R_{2})$$
(5)

#### 8.2.2.2 Setting V<sub>OUT2</sub> Using the VSEL Feature

A  $V_{OUT}$  level, different as set with  $R_1$  and  $R_2$  (see *Setting the Adjustable Output Voltage*), can be forced by connecting  $R_3$  between FB and RS pins and pulling VSEL High.  $R_3$  is calculated using Equation 6.

$$R_3 = \frac{V_1 \cdot R_1 \cdot R_2^2}{(V_2 - V_1) \cdot (R_1 \cdot R_2 + R_2^2)} \quad \text{for} \quad (V_2 > V_1)$$

where:

V1 is the lower level output voltage and

V<sub>2</sub> the higher level output voltage.

#### 8.2.2.3 Output Filter Selection

The TPS62480 is internally compensated and optimized to work for a certain range of L-C combinations. The recommended minimum output capacitance is 4 x 22  $\mu$ F, that can be ceramic capacitors exclusively. A larger value of C<sub>OUT</sub> might be needed for V<sub>OUT</sub> ≤ 1.8V, to improve transient response performance, as well as for V<sub>OUT</sub> > 3.3 V to compensate for voltage bias effects of the ceramic capacitors. The other way round, using of an additional feed forward capacitor can help reducing amount of output capacitance that is needed to achieve a certain transient response target (see *Output Capacitor Selection*).

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(6)

# TPS62480

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#### 8.2.2.4 Inductor Selection

The TPS62480 is designed to operate with two inductors of nominal 470 nH each. Inductors must be selected for adequate saturation current and for low dc resistance (DCR). The minimum inductor current rating  $I_{L(min)}$  that is needed under static load conditions calculates using Equation 7 and Equation 8. A current imbalance of 10% is incorporated.

$$I_{L(min)} = I_{PEAK(max)} = \frac{1.1 \cdot I_{OUT(max)}}{2} + \frac{\Delta I_{L(max)}}{2}$$

$$\Delta I_{L(max)} = V_{OUT} \left( \frac{1 - \frac{V_{OUT}}{V_{IN}}}{L_{(min)} \cdot f_{SW}} \right)$$
(8)

Choosing  $V_{IN} = 2 V_{OUT}$ , this calculation provides the minimum saturation current of the inductor needed. Additional margin is recommended to cover dynamic overshoot due to load transients. For low profile solutions, the physical inductor size and the power losses have to be traded off. Smallest solution size gives less efficiency and thermal performance due to larger DCR and/or core losses. The inductors shown in Table 2 have been tested with the TPS62480:

TYPE	INDUCTANC	CURRENT RATIN	NG MIN/TYP [A]	DCR MAX	DIMENSIONS (LxBxH)	MANUFACTURER	
TYPE	E [µH]	ΔL/L = 30%	ΔT = 40K	[mΩ]	[mm]	MANUFACIURER	
DFE201612E-R47M	0.47 ±20%	5.5/6.1	4.5/5.0	26	2.0 x 1.6 x 1.2	токо	
DFE252012F-R47M	0.47 ±20%	6.7/7.4	4.9/5.8	22	2.5 x 2.0 x 1.2	ТОКО	
DFE252010F-R47M	0.47 ±20%	6.0/6.6	4.4/5.2	27	2.5 x 2.0 x 1.0	ТОКО	
HMLQ25201B- R47MSR-11	0.47 ±20%	5.6/6.2	4.2/4.7	28	2.5 x 2.0 x 1.2	CYNTEC	
HMLQ20161T- R47MDR-11	0.47 ±20%	4.4/4.9	4.0/4.4	32	2.0 x 1.6 x 1.0	CYNTEC	
GLCLMR4701A	0.47 ±20%	3.6/4.5	3.8/4.7	32	2.5 x 2.0 x 1.2	ALPS	
GLCLKR4701A	0.47 ±20%	3.5/4.4	3.7/4.6	38	2.5 x 2.0 x 1.0	ALPS	
XFL4015-471ME	0.47 ±20%	6.6	11.2	8.36	4.0 x 4.0 x 1.5	COILCRAFT	

# Table 2. List of Inductors

### 8.2.2.5 Output Capacitor Selection

The TPS62480 provides a wide output voltage range of 0.6 V to 5.5 V. While stability is a critical criteria for the output filter selection, the output capacitor value also determines transient response behavior, ripple and accuracy of V<sub>OUT</sub>. The internal compensation is designed for an output capacitance range from about 50  $\mu$ F to 150  $\mu$ F effectively. Since ceramic capacitors are used preferably, this translates into nominal values of 4 x 22  $\mu$ F to 4 x 47  $\mu$ F and mainly depends on the output voltage. The following values are recommended:

	V <sub>OUT</sub> ≤ 1.0V	1.0V ≤ V <sub>OUT</sub> ≤ 3.3V	V <sub>OUT</sub> ≥ 3.3V
2x22µF			
4x22µF		$\checkmark$	
4x47µF	$\checkmark$	$\checkmark$	$\checkmark$
6x47µF			

#### Table 3. Recommended Output Capacitor Values (nominal)



Beyond the recommendations in Table 3, other values can be chosen and might be suitable depending on VOUT and actual effective capacitance. In such case, stability needs to be checked within the actual environment.

Even if the output capacitance is sufficient for stability, a different value might be desirable to improve the transient response behavior. Table 4 can be used to determine capacitor values for specific transient response targets:

Output Voltage [V]	Dutput Voltage [V] Load Step [A] Output Capac		Feedforward Capacitor <sup>(1)</sup>		Fransient Accuracy
				±mV	±%
4.0	0 - 3	4 47.5	-	50	5
1.0	3 - 6	- 4 x 47μF		50	5
1.8	0 - 3	1 00 F	00. F	50	3
	3 - 6	- 4 x 22μF	36pF	50	3
2.5	0 - 3	4 00. F	20-F	62	2.5
	3 - 6	- 4 x 22μF	36pF	50	2
3.3	0 - 3	4 47.15	20- F	100	3
	3 - 6	- 4 x 47μF	36pF	80	2.5

 Table 4. Recommended Output Capacitor Values (nominal)

(1) The values in the table are nominal values. The effective capacitance can differ significantly, depending on package size, voltage rating and dielectric material.

The architecture of the TPS62480 allows the use of tiny ceramic output capacitors with low equivalent series resistance (ESR). These capacitors provide low output voltage ripple and are recommended. To keep its low resistance up to high frequencies and to get narrow capacitance variation with temperature, it is recommended to use X5R or X7R dielectrics. Using even higher values than demanded for stability and transient response has further advantages like smaller voltage ripple and tighter dc output accuracy in Power Save Mode.

#### 8.2.2.6 Input Capacitor Selection

The input current of a buck converter is pulsating. Therefore, a low ESR input capacitor is required to prevent large voltage transients at the source but to provide peak currents to the device. The recommended value for most applications is  $2 \times 22 \mu$ F, split between the VIN1 and VIN2 inputs and placed as close as possible to these pins and PGND pins. If additional capacitance is needed, it can be added as bulk capacitance. To ensure proper operation, the effective capacitance at the VIN pins must not fall below  $2 \times 5 \mu$ F.

Low ESR multilayer ceramic capacitors are recommended for best filtering. Increasing with input voltage, the dc bias effect reduces the nominal capacitance value significantly. To decrease input ripple current further, larger values of input capacitors can be used.

### 8.2.2.7 Soft Start Capacitor Selection

The soft start ramp time can be set externally connecting a capacitor between the SS/TR and AGND pins. The capacitor value  $C_{SS}$  that is needed to get a specific rising time  $\Delta t_{SS}$  calculates as:

$$C_{SS} = \Delta t_{SS} \cdot \frac{5.25 \mu A}{0.6 V}$$
(9)

Since the device has an internal delay time  $\Delta t_{DELAY}$  from EN=High to start switching, the overall startup time is longer as shown in Figure 7.



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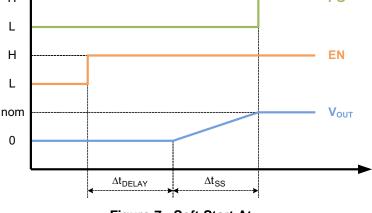


Figure 7. Soft Start  $\Delta t_{SS}$ 

If very large output capacitances are used (e.g. >4x47µF), the use of a soft start capacitor is mandatory to secure complete startup.

# 8.2.2.8 Tracking

For values up to 0.6V, an external voltage, connected to the SS/TR pin, drives the voltage level at the FB pin. In doing so, the voltage at the FB pin is directly proportional to the voltage at the SS/TR pin.

When choosing the resistive divider proportion according to Equation 10,  $V_{OUT}$  tracks  $V_{TR}$  simultaneously.

$$\frac{\mathsf{R}_1}{\mathsf{R}_2} = \frac{\mathsf{R}_3}{\mathsf{R}_4} \tag{10}$$

FB

**TPS62480** 

SS/TR

V<sub>OUT</sub>

R1

R2



0.6V

0V

Following the example of Setting the Adjustable Output Voltage with  $V_{OUT} = 1.8 \text{ V}$ ,  $R_1 = 240 \text{ k}\Omega$  and  $R_2 = 120 \text{ k}\Omega$ , Equation 11 and Equation 12 calculate R3 and R4, connected to the SS/TR pin. Different to the resistive divider at the FB pin, a larger current must be chosen, to avoid a tracking offset caused by the 5.25 µA current that flows out of the SS/TR pin. Assuming a 250  $\mu$ A current, R<sub>4</sub> calculates as follows:



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(11)

$$\mathsf{R}_4 = \frac{0.6\mathsf{V}}{250\mu\mathsf{A}} = 2.4\mathsf{k}\Omega$$

R<sub>3</sub> calculates now rearranging Equation 10:

$$\mathsf{R}_3 = \mathsf{R}_4 \cdot \frac{\mathsf{R}_1}{\mathsf{R}_2} = 2.4 \mathsf{k}\Omega \cdot \frac{240 \mathsf{k}\Omega}{120 \mathsf{k}\Omega} = 4.8 \mathsf{k}\Omega \tag{12}$$

However, the following limitations can influence the tracking accuracy:

- The upper limit of the SS/TR voltage that can be tracked is about 0.6V. Since it is detected internally by a comparator, process variation and ramp speed can cause up to ±30 mV different threshold.
- In case that the voltage at SS/TR ramps up immediately when VIN is supplied or EN is set High, the internal startup delay, Δt<sub>DELAY</sub>, delays the ramp of V<sub>OUT</sub>. The internal ramp starts after Δt<sub>DELAY</sub> at the voltage level, which is actually present at the SS/TR pin.
- The tracking down speed is limited by the RC time constant of the internal output discharge (always connected when tracking down) and the actual load with the output capacitance. Note: The device tracks down with the same behavior for MODE High (Forced PWM) or Low (Auto PSM).

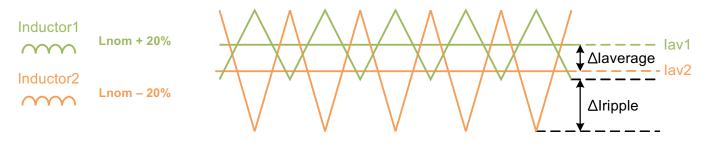
#### 8.2.2.9 Current Sharing

The TPS62480 is designed to share load current wisely between the 2 phases. The current imbalance is less than 15% over VIN and temperature range and independent on inductor mismatch.

However, the mismatch between the two inductors itself causes additional imbalance of the average inductor currents, caused by different ripple current. The mismatch can be calculated as shown in the following example, assuming that the nominal inductance of 470 nH can vary  $\pm 20\%$ , the switching frequency is 2 MHz. Converting 5 V into 2.5 V gives a duty cycle of 0.5, which effects maximum ripple current. Since the ripple current is calculated with:

$$I_{ripple} = V_{OUT} \left( \frac{1 - \frac{V_{OUT}}{V_{IN}}}{f_{SW} \cdot L} \right)$$
(13)

the ripple currents in the two inductors are calculated with  $I_{ripple1} = 1.69$  A and  $I_{ripple2} = 1.1$  A which gives a  $\Delta I_{ripple}$  of 0.59 A as worst case number based on the maximum inductor tolerance. Figure 9 shows the relation of the two inductor currents in such case.





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The difference in the average current is calculated using:

$$\Delta I_{av} = \frac{\Delta I_{ripple}}{2}$$
(14)

In this worst case calculation the average inductor current mismatch is 0.295A, less than 10% at the full load current of 3A per phase.

#### 8.2.2.10 Thermal Good

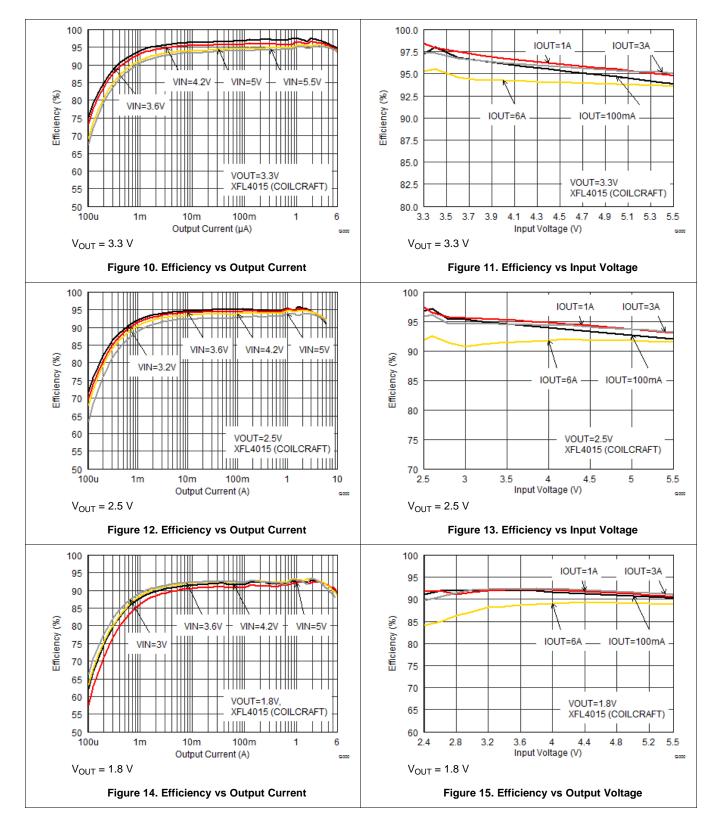
The Thermal Good pin provides an open drain output. The logic level is given by the pull up source which can be VOUT. In this case, TG goes or stays Low, when the device switches off due to EN, UVLO or Thermal Shutdown.

When using an independent source for the pull up logic, the logic behavior at shutdown differs, because the TG pin internally goes high impedance. As before, TG goes Low when TG threshold is reached, but goes back High in the event of being switched off (e.g. Thermal Shutdown).



#### 8.2.3 Application Curves

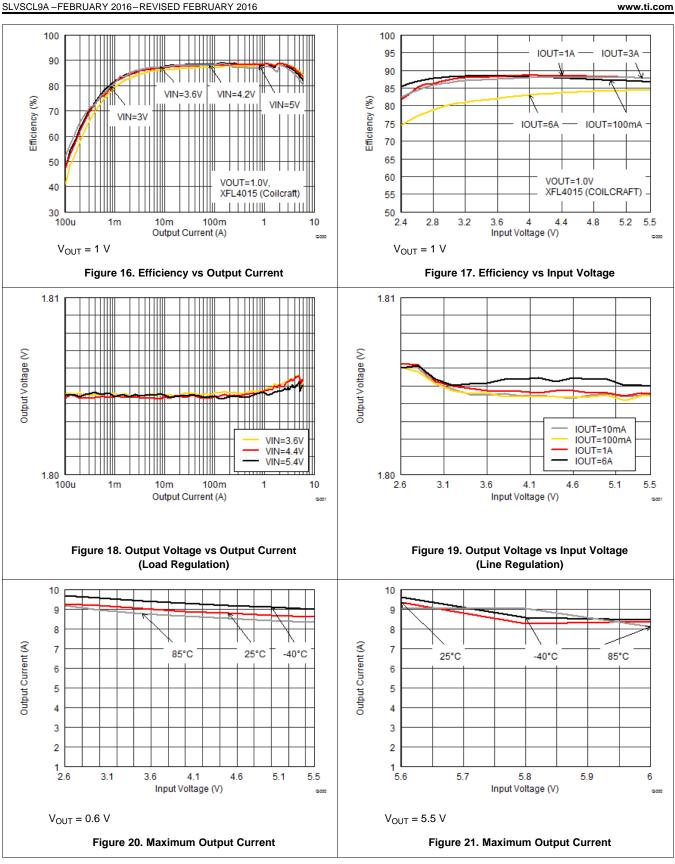
 $V_{IN}$ = 3.6 V,  $V_{OUT}$  = 1.8V (R1 / R2 = 240 k $\Omega$  / 120 k $\Omega$ ),  $T_A$  = 25°C, (unless otherwise noted)



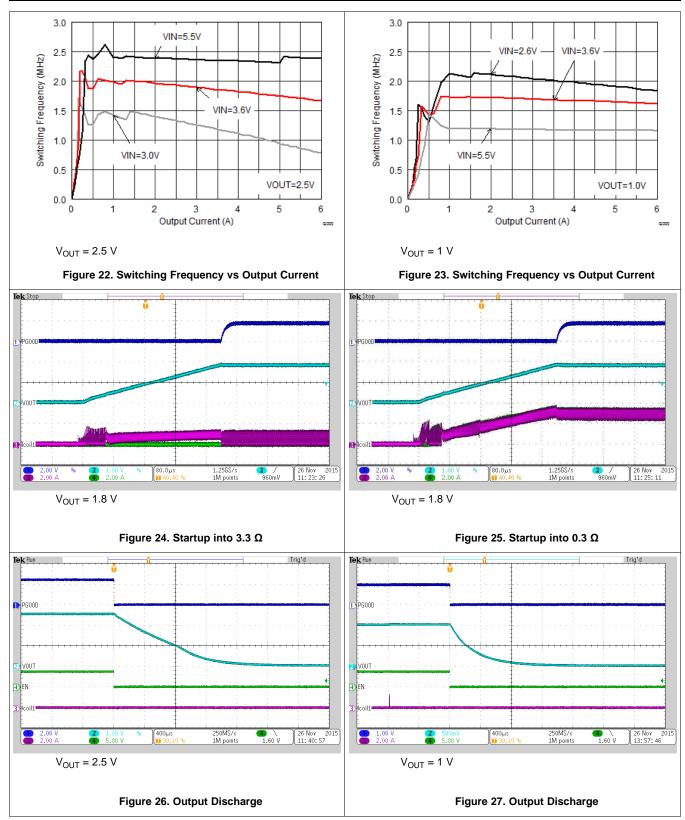


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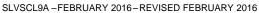


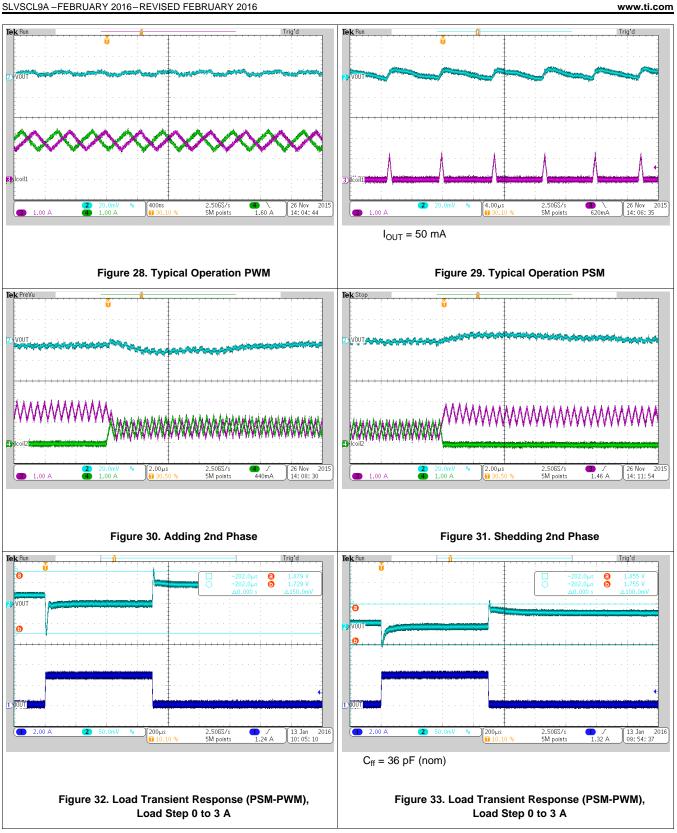




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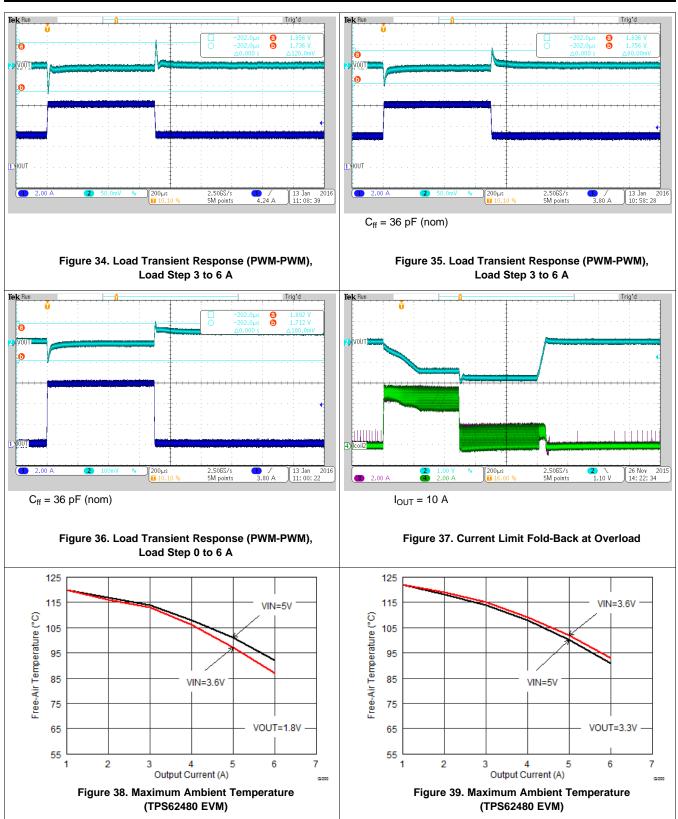






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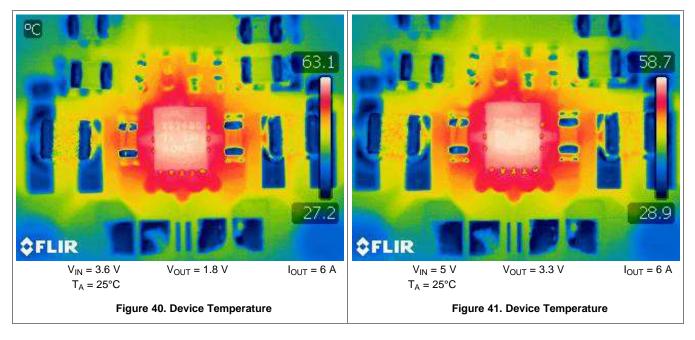


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### 8.3 System Examples

This section provides typical schematics for commonly used output voltages values.

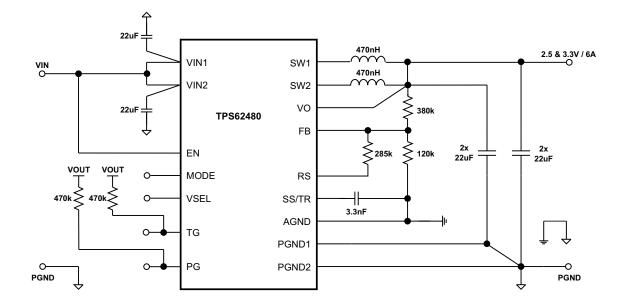


Figure 42. A typical 2.5 V & 3.3 V, 6 A Power Supply

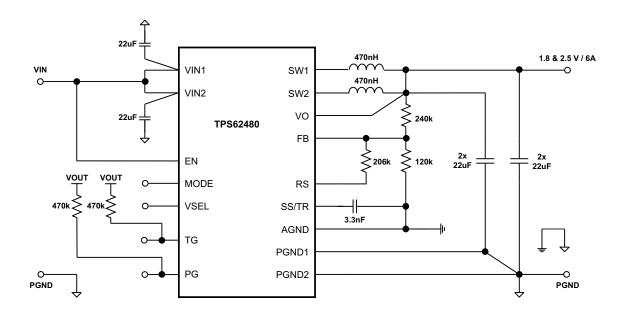


Figure 43. A typical 1.8 V & 2.5 V, 6 A Power Supply



## System Examples (continued)

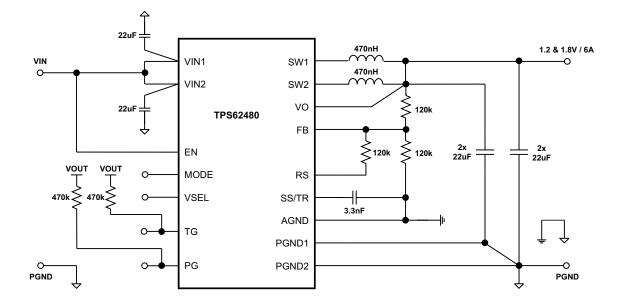


Figure 44. A typical 1.2 V & 1.8 V, 6 A Power Supply

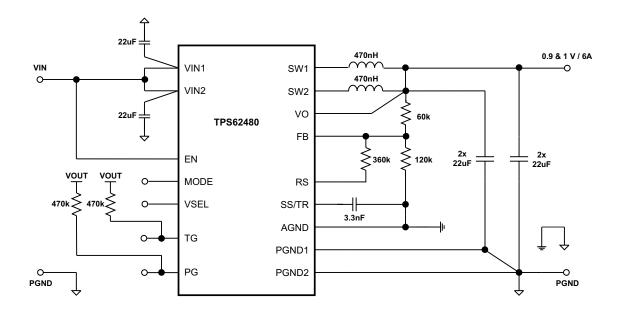


Figure 45. A typical 0.9 V & 1 V, 6 A Power Supply

## 9 Power Supply Recommendations

The TPS62480 is designed to operate from a 2.4-V to 5.5-V input voltage supply. The input power supply's output current needs to be rated according to the output voltage and the output current of the power rail application.



# 10 Layout

### 10.1 Layout Guidelines

A recommended PCB layout for the TPS62480 dual phase solution is shown below. It ensures best electrical and optimized thermal performance considering the following important topics:

- The input capacitors must be placed as close as possible to the appropriate pins of the device. This provides low resistive and inductive paths for the high di/dt input current. The input capacitance is split, as is the  $V_{IN}$  connection, to avoid interference between the input lines.

- The SW node connection from the IC to the inductor conducts high currents. It should be kept short and can be designed in parallel with an internal or bottom layer plane, to provide low resistance and enhanced thermal behavior.

- The V<sub>OUT</sub> regulation loop is closed with  $C_{OUT}$  and its ground connection. To avoid PGND noise crosstalk, PGND is kept split for the regulation loop. If a ground layer or plane is used, a direct connection by vias, as shown, is recommended. Otherwise the connection of  $C_{OUT}$  to GND must be short for good load regulation.

- The use of thermal (filled) vias underneath the device is recommended for improved thermal performance.

- The FB node is sensitive to dv/dt signals. Therefore the resistive divider should be placed close to the FB (and RS pin in case of using R<sub>3</sub>) pin, avoiding long trace distance.

For more detailed information about the actual 4 layer EVM solution, see SLVUAI6.

### 10.2 Layout Example

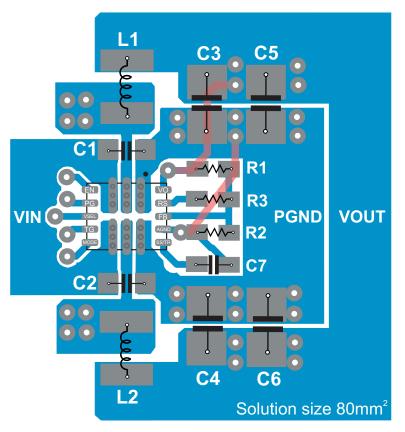


Figure 46. TPS62480 Board Layout



# **11** Device and Documentation Support

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- **Design Support TI's Design Support** Quickly find helpful E2E forums along with design support tools and contact information for technical support.

#### 11.3 Trademarks

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#### 11.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

## 11.5 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

## 12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



22-Mar-2016

# PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
TPS62480RNCR	ACTIVE	VQFN-HR	RNC	16	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	62480	Samples
TPS62480RNCT	ACTIVE	VQFN-HR	RNC	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	62480	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW**: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between

the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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# PACKAGE MATERIALS INFORMATION

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# TAPE AND REEL INFORMATION





# QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	-	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS62480RNCT	VQFN- HR	RNC	16	250	180.0	12.4	2.8	3.3	1.2	8.0	12.0	Q1

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# PACKAGE MATERIALS INFORMATION

1-Apr-2016



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS62480RNCT	VQFN-HR	RNC	16	250	210.0	185.0	35.0

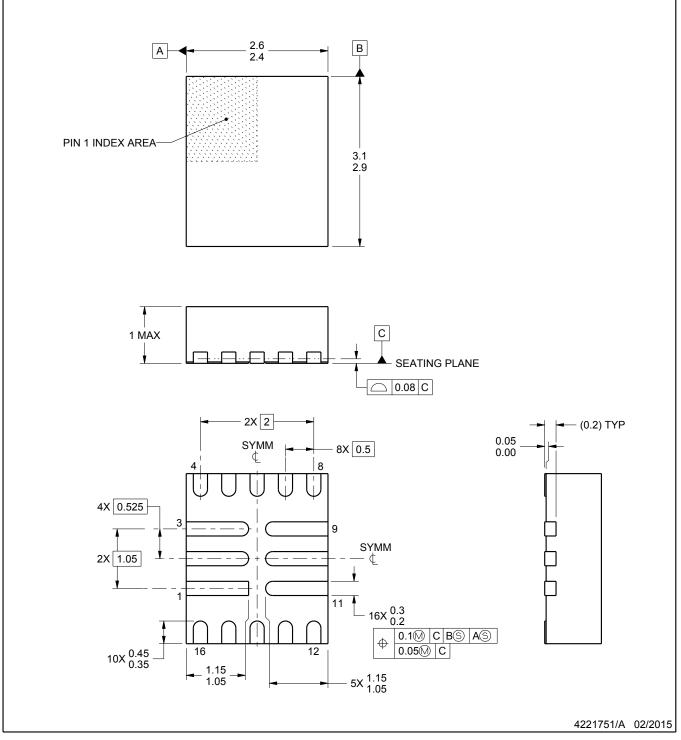
# **RNC0016A**



# **PACKAGE OUTLINE**

# VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice.

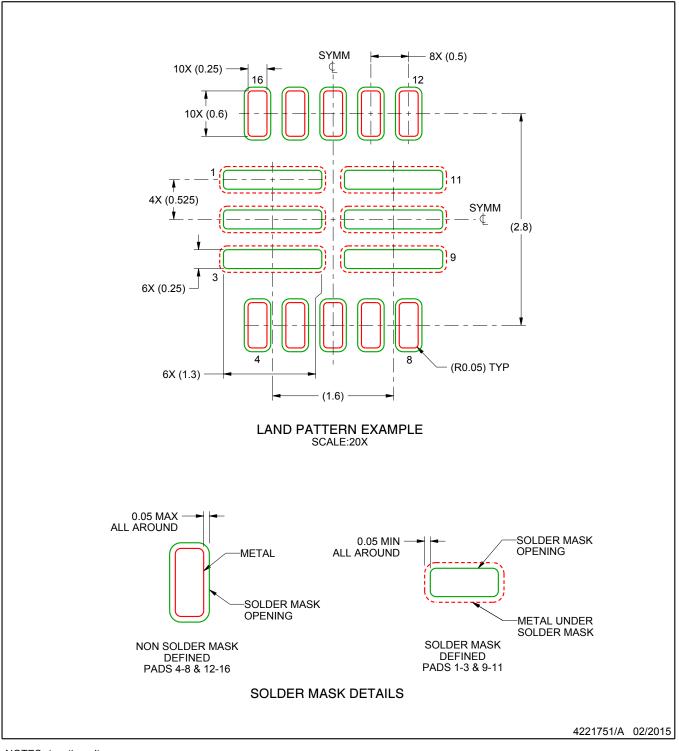


# **RNC0016A**

# **EXAMPLE BOARD LAYOUT**

# VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

3. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

4. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

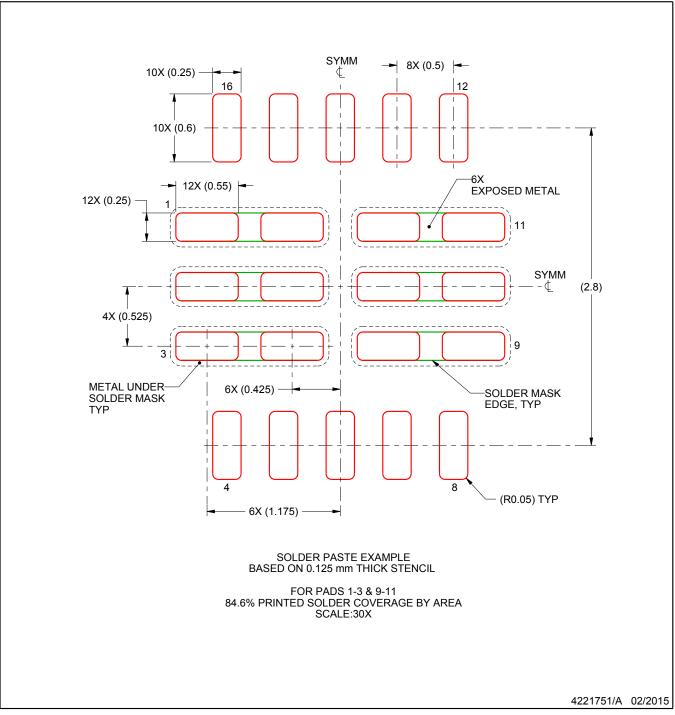


# **RNC0016A**

# **EXAMPLE STENCIL DESIGN**

# VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

5. For alternate stencil design recommendations, see IPC-7525 or board assembly site preference.



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